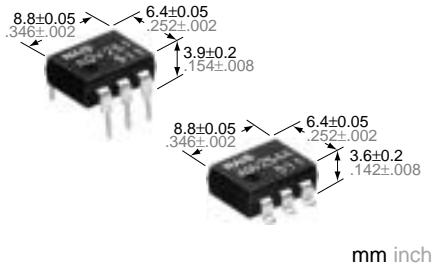


NAiS

**HE (High-function Economy)
Type
[1-Channel (Form A) Type]**

PhotoMOS RELAYS



mm inch

FEATURES

1. **Highly sensitive and low on-resistance**
2. **Controls various types of loads such as relays, motors, lamps and solenoids.**
3. **Optical coupling for extremely high isolation**
5,000 Vrms I/O isolation available.
4. **Low-level off state leakage current**
5. **Eliminates the need for a power supply to drive the power MOSFET**
A power supply used to drive the power MOSFET is unnecessary because of the built-in optoelectronic device. This results in easy circuit design and small PC board area.
6. **Low thermal electromotive force (Approx. 1 µV)**

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Data communication equipment

TYPES

1. I/O isolation voltage: 1,500 V AC

Output rating*		Part No.			Packing quantity	
		Through hole terminal	Surface-mount terminal			
Load voltage	Load current	Tube packing style	Tape and reel packing style		Tube	Tape and reel
			Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
40 V	500 mA	AQV251	AQV251A	AQV251AX	AQV251AZ	
60 V	400 mA	AQV252	AQV252A	AQV252AX	AQV252AZ	
100 V	350 mA	AQV255	AQV255A	AQV255AX	AQV255AZ	
200 V	250 mA	AQV257	AQV257A	AQV257AX	AQV257AZ	
250 V	200 mA	AQV253	AQV253A	AQV253AX	AQV253AZ	
400 V	150 mA	AQV254	AQV254A	AQV254AX	AQV254AZ	
1,000 V	30 mA	AQV259	AQV259A	AQV259AX	AQV259AZ	
1,500 V	20 mA	AQV258	AQV258A	AQV258AX	AQV258AZ	

2. I/O isolation voltage: Reinforced 5,000 V

Output rating*		Part No.			Packing quantity	
		Through hole terminal	Surface-mount terminal			
Load voltage	Load current	Tube packing style	Tape and reel packing style		Tube	Tape and reel
			Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
250 V	200 mA	AQV253H	AQV253HA	AQV253HAX	AQV253HAZ	
400 V	150 mA	AQV254H	AQV254HA	AQV254HAX	AQV254HAZ	

*Indicate the peak AC and DC values.

Note: For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV251(A)	AQV252(A)	AQV255(A)	AQV257(A)	AQV253(A)	AQV254(A)	AQV259(A)	AQV258(A)	AQV253H(A)	AQV254H(A)	Remarks			
Input	LED forward current	I _F		50 mA													
	LED reverse voltage	V _R		3 V													
	Peak forward current	I _{FP}		1 A										f = 100 Hz, Duty factor +0.1%			
	Power dissipation	P _{in}		75 mW													
Output	Load voltage (peak AC)	V _L		40 V	60 V	100 V	200 V	250 V	400 V	1,000 V	1,500 V	250 V	400 V				
	Continuous load current	I _L		A	0.5 A	0.4 A	0.35 A	0.25 A	0.2 A	0.15 A	0.03 A	0.02 A	0.2 A	0.15 A			
				B	0.7 A	0.6 A	0.45 A	0.35 A	0.3 A	0.18 A	0.04 A	0.025 A	0.3 A	0.18 A			
		C		1.0 A	0.8 A	0.70 A	0.5 A	0.4 A	0.25 A	0.05 A	0.04 A	0.4 A	0.25 A	A connection: Peak AC, DC B, C connection: DC			
	Peak load current	I _{peak}		1.8 A	1.5 A	1.0 A	0.75 A	0.6 A	0.5 A	0.09 A	0.06 A	0.6 A	0.5 A	A connection: 100 ms (1 shot) V _L = DC			
	Power dissipation	P _{out}		360 mW													
	Total power dissipation	P _T		410 mW													
I/O isolation voltage		V _{iso}	1,500 V AC								5,000 V AC						
Temperature limits	Operating	T _{opr}	−40°C to +85°C −40°F to +185°F											Non-condensing at low temperatures			
	Storage	T _{stg}	−40°C to +100°C −40°F to +212°F														

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV251(A)	AQV252(A)	AQV255(A)	AQV257(A)	AQV253(A)	AQV254(A)	AQV259(A)	AQV258(A)	AQV253H(A)	AQV254H(A)	Condition				
Input	LED operate current	Typical	I _{Fon}	—	0.9 mA								1.4 mA	I _L = Max.				
		Maximum			3 mA													
	LED turn off current	Minimum	I _{Foff}	—	0.4 mA								1.3 mA	I _L = Max.				
		Typical			0.8 mA													
Output	LED dropout voltage	Typical	V _F	—	1.14 V**													
		Maximum			1.5 V													
	On resistance	R _{on}	A	0.6	0.74	1.8	2.6	5.5	12.4	85	345	5.5	12.4	I _F = 5 mA I _L = Max. Within 1 s on time				
		Maximum		1	1.4	2.5	4	8	16	200	500	8	16	I _F = 5 mA I _L = Max. Within 1 s on time				
		Typical	R _{on}	B	0.3	0.37	0.9	1.4	2.7	6.2	60	345	2.7	6.2				
		Maximum		0.5	0.7	1.25	2	4	8	100	500	4	8	I _F = 5 mA I _L = Max. Within 1 s on time				
	Off state leakage current	R _{on}	C	0.15	0.18	0.45	0.7	1.4	3.1	30	160	1.4	3.1	I _F = 5 mA I _L = Max. Within 1 s on time				
		Maximum		0.25	0.35	0.63	1	2	4	50	250	2	4	I _F = 0 V _L = Max.				
Transfer characteristics	Switching speed	Turn on time*	T _{on}	—	1 μA						10 μA		1 μA					
		Maximum		—	1.7 ms	1.4 ms	0.9 ms	1.5 ms	0.8ms	0.8ms	0.6ms	0.35 ms	2.4ms	1.8ms	I _F = 5 mA I _L = Max.			
	Turn off time*	T _{off}	—	3 ms						2 ms		1 ms		4 ms	3 ms			
		Maximum		—	0.07 ms	0.09 ms	0.1 ms	0.06 ms	0.05 ms	0.04 ms		0.06 ms		0.05 ms	I _F = 5 mA I _L = Max.			
	I/O capacitance	C _{iso}	—	0.2 ms										f = 1 MHz V _B = 0				
		Maximum		—	1.3 pF													
	Initial I/O isolation resistance	Minimum	R _{iso}	—	3 pF													
					1,000 M													
					500 V DC													

Note: Recommendable LED forward current

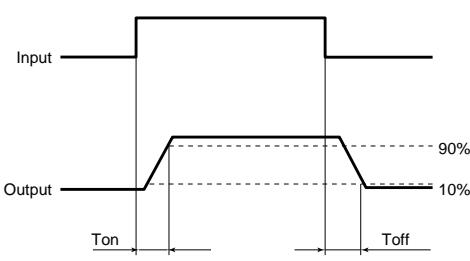
Standard type: 5 mA

Reinforced type: 5 to 10 mA

For type of connection, see Page 444.

**1.25 V at I_F = 50 mA

*Turn on/Turn off time



■ For Dimensions, see Page 440.

■ For Schematic and Wiring Diagrams, see Page 444.

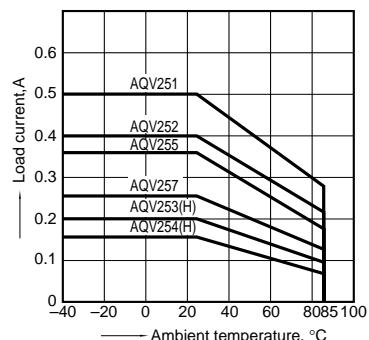
■ For Cautions for Use, see Page 449.

REFERENCE DATA

1.-(1) Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$;

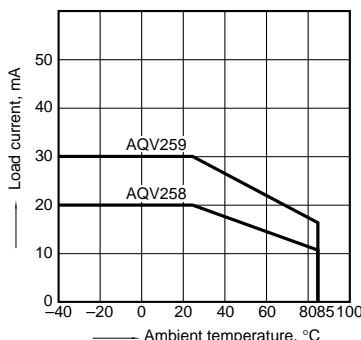
Type of connection: A



1.-(2) Load current vs. ambient temperature characteristics

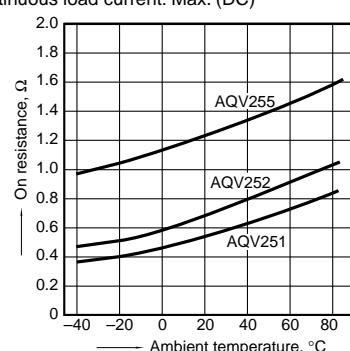
Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$;

Type of connection: A



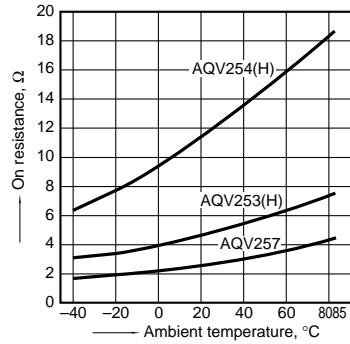
2.-(1) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA;
Continuous load current: Max. (DC)



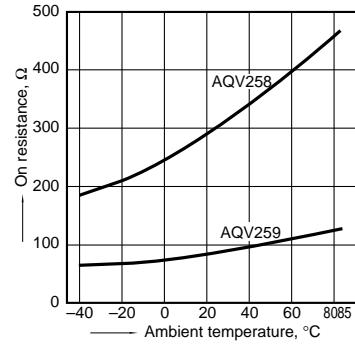
2.-(2) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA;
Continuous load current: Max. (DC)



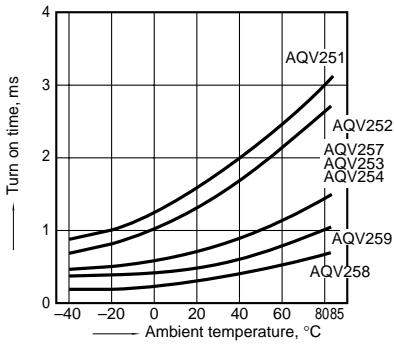
2.-(3) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA;
Continuous load current: 30 mA (DC)



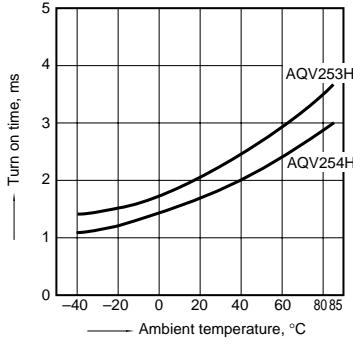
3.-(1) Turn on time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



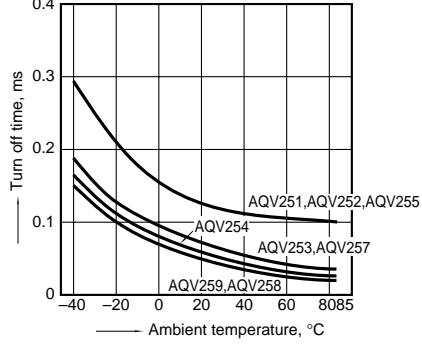
3.-(2) Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



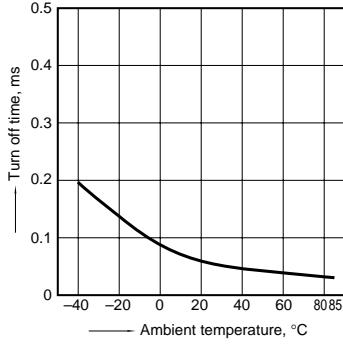
4.-(1) Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



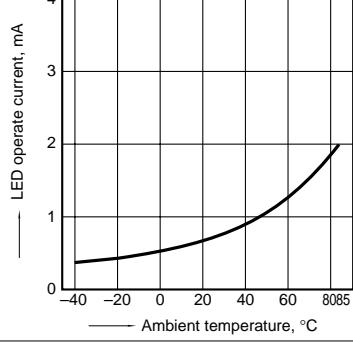
4.-(2) Turn off time vs. ambient temperature characteristics

Sample: AQV253H, AQV254H
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



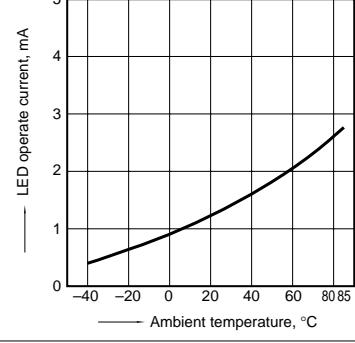
5.-(1) LED operate current vs. ambient temperature characteristics

Sample: AQV251, AQV252, AQV253, AQV254, AQV259; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



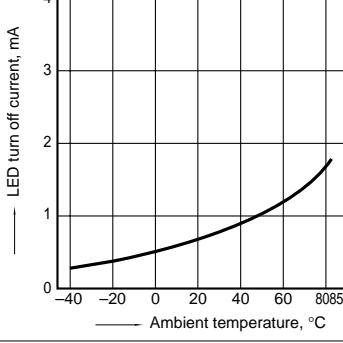
5.-(2) LED operate current vs. ambient temperature characteristics

Sample: AQV253H, AQV254H; Load voltage: Max. (DC);
Continuous load current: Max. (DC)

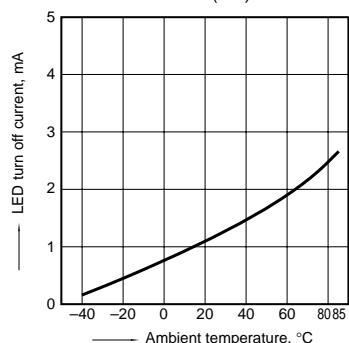


6.-(1) LED turn off current vs. ambient temperature characteristics

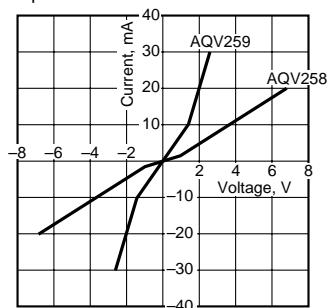
Sample: AQV251, AQV252, AQV253, AQV254, AQV259; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



6. -(2) LED turn off current vs. ambient temperature characteristics
Sample: AQV251, AQV252, AQV253, AQV254, AQV259; Load voltage: Max. (DC); Continuous load current: Max. (DC)

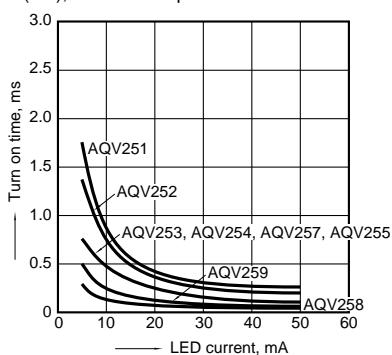


8.-(2) Voltage vs. current characteristics of output at MOS portion
Sample: AQV259
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



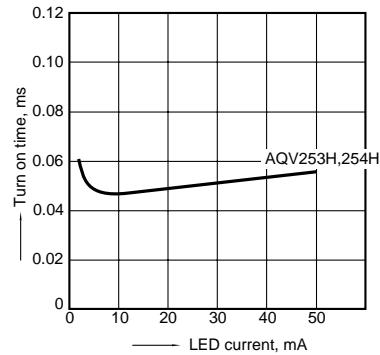
10-(1). LED forward current vs. turn on time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F

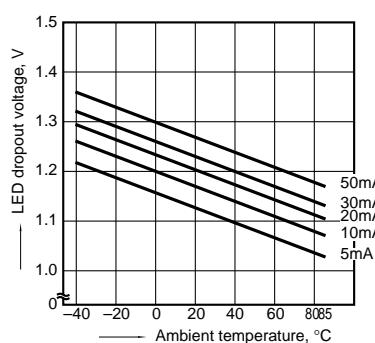


11-(2). LED forward current vs. turn off time characteristics

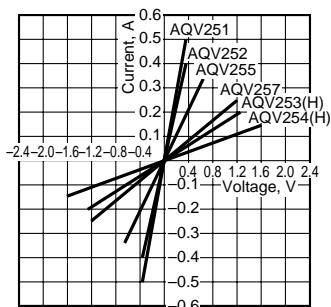
Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



7. LED dropout voltage vs. ambient temperature characteristics
LED current: 5 to 50 mA

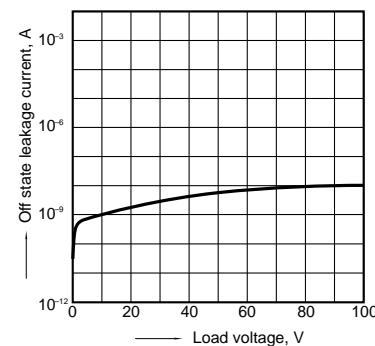


8.-(1) Voltage vs. current characteristics of output at MOS portion
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



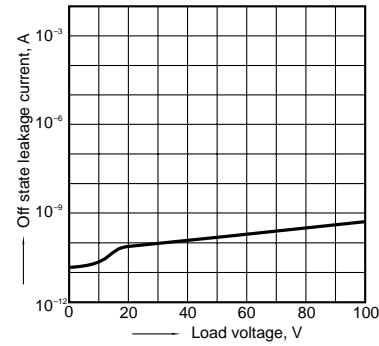
9-(1). Off state leakage current

Sample: AQV259;
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



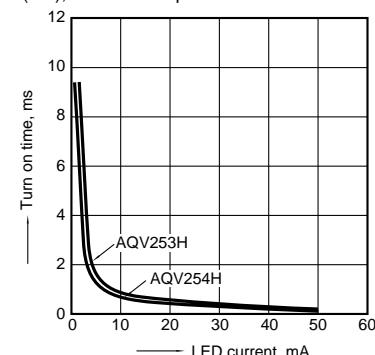
9-(2). Off state leakage current

Sample: AQV254H;
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



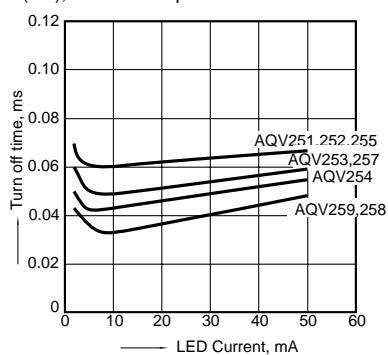
10-(2). LED forward current vs. turn on time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



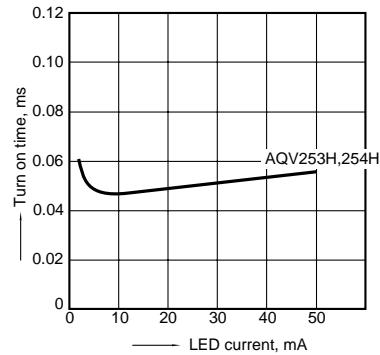
11-(1). LED forward current vs. turn off time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



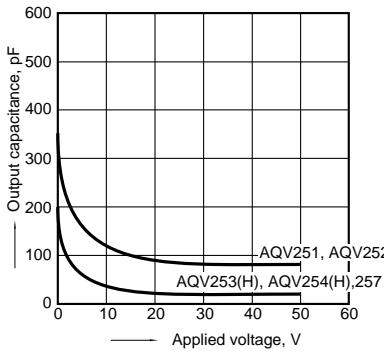
11-(2). LED forward current vs. turn off time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



12-(1) Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



12-(2) Applied voltage vs. output capacitance characteristics

Sample: AQV259;
Measured portion: between terminals 4 and 6;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F

